

DATA SHEET

TDA4670

Picture Signal Improvement (PSI) circuit

Product specification
Supersedes data of May 1991
File under Integrated Circuits, IC02

1996 Dec 11

Picture Signal Improvement (PSI) circuit

TDA4670

FEATURES

- Luminance signal delay from 20 to 1100 ns (minimum step 45 ns)
- Luminance signal peaking with selectable symmetrical overshoots
- 2.6 or 5 MHz peaking centre frequency and selectable degree of peaking (–3, 0, +3 and +6 dB)
- Selectable noise reduction by coring
- Handles negative and positive colour-difference signals
- Selectable Colour Transient Improvement (CTI) to decrease the colour-difference signal transient times to those of the high frequency luminance signals
- Selectable 5 or 12 V sandcastle input voltage
- All controls selected via the I²C-bus
- Timing pulse generation for clamping and delay time control synchronized by sandcastle pulse
- Automatic luminance signal delay correction using a control loop
- Luminance and colour-difference input signal clamping with coupling capacitor
- 4.5 to 8.8 V supply voltage range
- Minimum of external components required.



GENERAL DESCRIPTION

The TDA4670 delays the luminance signal and improves colour-difference signal transients. Additionally, the luminance signal can be improved by peaking and noise reduction (coring).

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V _P	supply voltage (pins 1 and 5)	4.5	5	8.8	V
I _{P(tot)}	total supply current	31	41	52	mA
t _{d(Y)}	Y signal delay time	20	–	1130	ns
V _{i(VBS)}	composite Y input signal (peak-to-peak value, pin 16)	–	450	640	mV
V _{i(CD)(p-p)}	colour-difference input signal (peak-to-peak value)				
	±(R – Y) on pin 3	–	1.05	1.48	V
	±(R – Y) on pin 7	–	1.33	1.88	V
G _Y	gain of Y channel	–	–1	–	dB
G _{CD}	gain of colour-difference channel	–	0	–	dB
T _{amb}	operating ambient temperature	0	–	70	°C

ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
TDA4670	DIP18	plastic dual in-line package; 18 leads (300 mil)	SOT102-1

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BLOCK DIAGRAM

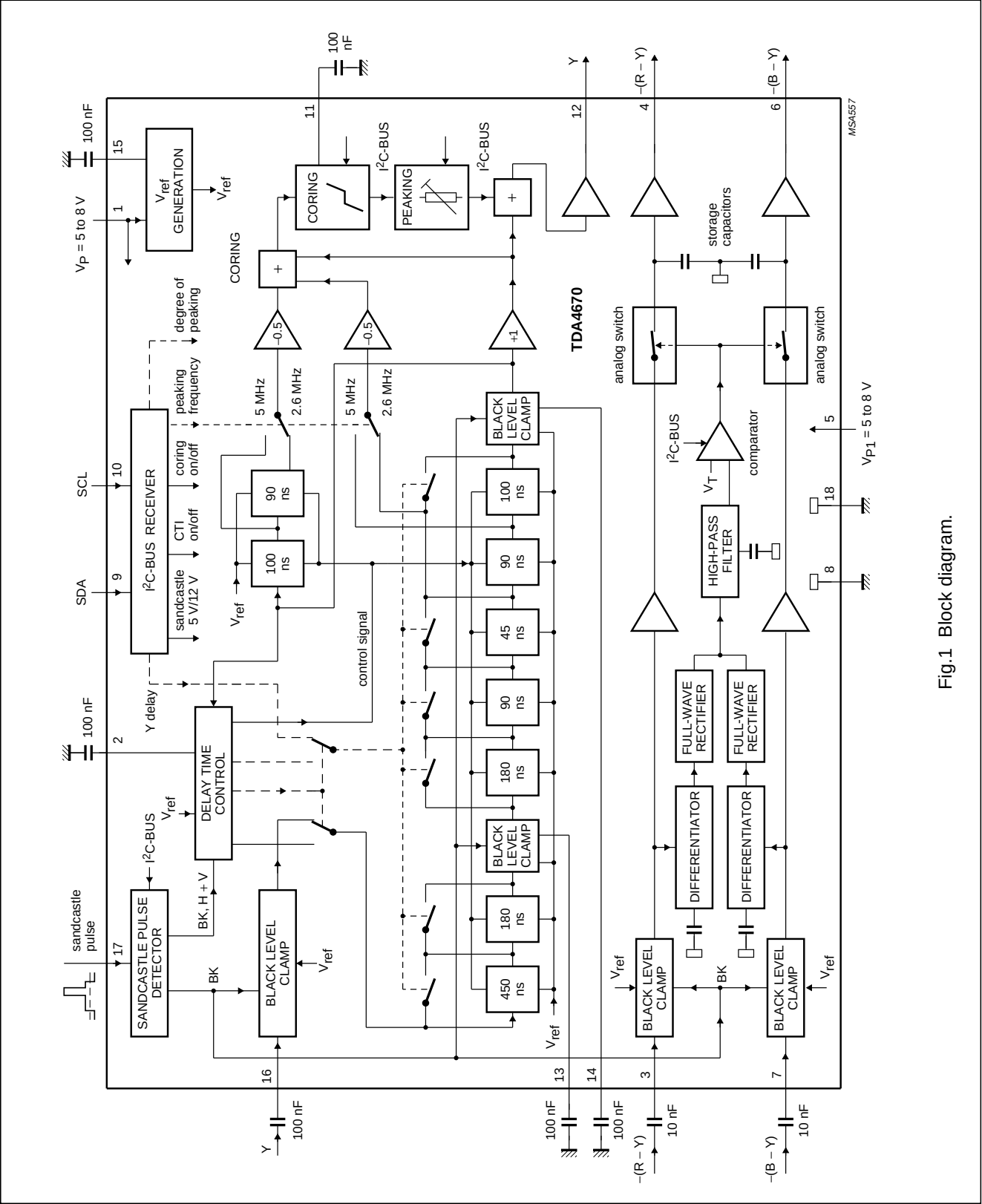


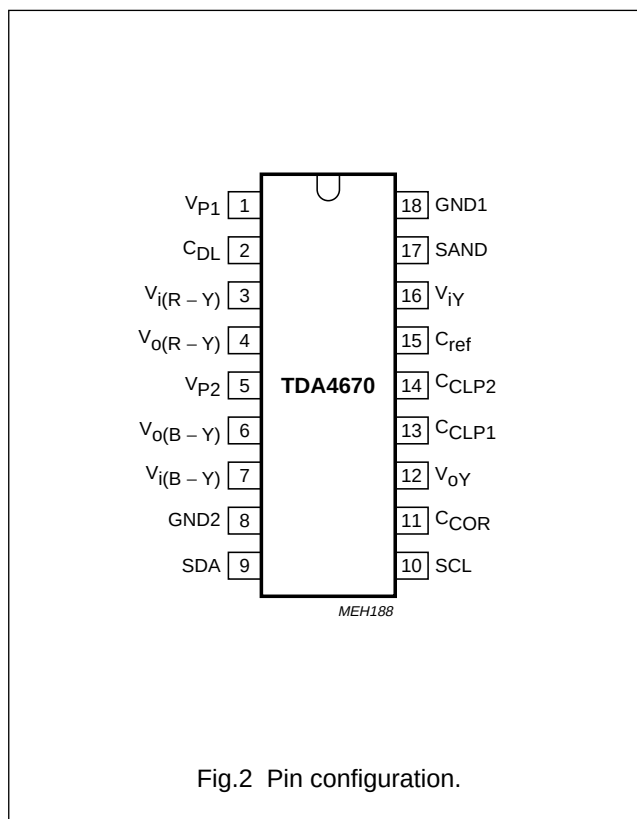
Fig.1 Block diagram.

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PINNING

SYMBOL	PIN	DESCRIPTION
V _{P1}	1	positive supply voltage 1
C _{DL}	2	capacitor of delay time control
V _{i(R-Y)}	3	$\pm(R - Y)$ colour-difference input signal
V _{o(R-Y)}	4	$\pm(R - Y)$ colour-difference output signal
V _{P2}	5	positive supply voltage 2
V _{o(B-Y)}	6	$\pm(B - Y)$ colour-difference output signal
V _{i(B-Y)}	7	$\pm(B - Y)$ colour-difference input signal
GND2	8	ground 2 (0 V)
SDA	9	I ² C-bus serial data input/output
SCL	10	I ² C-bus serial clock input
C _{COR}	11	coring capacitor
V _{oY}	12	delayed luminance output signal
C _{CLP1}	13	black level clamping capacitor 1
C _{CLP2}	14	black level clamping capacitor 2
C _{ref}	15	capacitor of reference voltage
V _{iY}	16	luminance input signal
SAND	17	sandcastle pulse input
GND1	18	ground 1 (0 V)



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FUNCTIONAL DESCRIPTION

The TDA4670 contains luminance signal processing and colour-difference signal processing. The luminance signal section comprises a variable integrated luminance delay line with luminance signal peaking and noise reduction by coring.

The colour-difference section consists of a transient improvement circuit to decrease the rise and fall times of the colour-difference signal transients. All functions and parameters are controlled via the I²C-bus.

Y-signal path

The video and blanking signal is AC-coupled to the input at pin 16. Its black porch is clamped to a DC reference voltage to ensure the correct operating range of the luminance delay stage.

The luminance delay line consists of all-pass filter sections with delay times of 45, 90, 100, 180 and 450 ns (see Fig.1). The luminance signal delay is controlled via the I²C-bus in steps of 45 ns in the range of 20 to 1100 ns, this ensures that the maximum delay difference between the luminance and colour-difference signals is ± 22.5 ns.

An automatic luminance delay time adjustment in an internal control loop (with the horizontal frequency as a reference) is used to correct changes in the delay time, due to component tolerances. The control loop is automatically enabled between the burst key pulses of lines 16 (330) and 17 (331) during the vertical blanking interval. The control voltage is stored in the capacitor C_{DL} connected to pin 2.

The peaking section uses a transversal filter circuit with selectable centre frequencies of 2.6 and 5 MHz.

It provides selectable degrees of peaking of -3, 0, +3 and +6 dB and a noise reduction by coring, which attenuates the high-frequency noise introduced by peaking.

The output buffer stage ensures a low-ohmic VBS output signal on pin 12 ($<160 \Omega$). The gain of the luminance signal path from pin 16 to pin 12 is unity.

An oscillation signal of the delay time control loop is present on output pin 12 instead of the VBS signal during the vertical blanking interval in lines 16 (330) to 18 (332). Therefore, this output signal should not be applied for synchronization.

Colour-difference signal paths

The colour-difference input signals (on pins 3 and 7) are clamped to a reference voltage.

Each colour-difference signal is fed to a transient detector and to an analog signal switch with an attached voltage storage stage.

The transient detectors consist of differentiators and full-wave rectifiers. The output voltages of both transient detectors are added and then compared in a comparator. This comparator controls both following analog signal switches simultaneously.

The analog signal switches are in an open position at a certain value of transient time; the held value (held by storage capacitors) is then applied to the outputs. The switches close to rapidly accept the actual signal levels at the end of these transients. The improved transient time is approximately 100 ns long and independent of the input signal transient time.

Colour-difference paths are independent of the input signal polarity and have a gain of unity.

The CTI functions are switched on and off via the I²C-bus.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134). V_{P1} and V_{P2} as well as GND1 and GND2 connected together.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{P1}	supply voltage (pin 1)		0	8.8	V
V_{P2}	supply voltage (pin 5)		0	8.8	V
P_{tot}	total power dissipation		0	0.97	W
T_{stg}	storage temperature		-25	+150	°C
T_{amb}	operating ambient temperature		0	70	°C
V_{ESD}	electrostatic handling for pins 9 and 10 for other pins	note 1	— — —	+300 -500 ±500	V V V

Note

1. Equivalent to discharging a 200 pF capacitor through a 0 Ω series resistor.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient in free air	82	K/W

CHARACTERISTICS

$V_{P1} = V_{P2} = 5$ V; nominal video amplitude $V_{VB} = 315$ mV; $t_H = 64$ μ s; $t_{BK} = 4$ μ s (burst key); $T_{amb} = 25$ °C; measurements taken in Fig.4; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{P1}	supply voltage (pin 1)		4.5	5	8.8	V
V_{P2}	supply voltage (pin 5)		4.5	5	8.8	V
$I_{P(tot)}$	total supply current		31	41	52	mA
Y-signal path						
$V_{i(Y)(p-p)}$	VBS input signal on pin 16 (peak-to-peak value)		—	450	640	mV
V_{16}	black level clamping voltage		—	3.1	—	V
I_{16}	input current	during clamping	±95	—	±190	μ A
		outside clamping	—	—	±0.1	μ A
R_{16}	input resistance	outside clamping	5	—	—	M Ω
C_{16}	input capacitance		—	3	10	pF
$t_{d(Y)(max)}$	maximum Y delay time	set via I ² C-bus	1070	1100	1130	ns
$t_{d(Y)(min)}$	minimum Y delay time	set via I ² C-bus	—	20	—	ns

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$\Delta t_{d(Y)}$	minimum delay step	set via I ² C-bus	40	45	50	ns
	group delay time difference	f = 0.5 to 5 MHz; maximum delay	–	0	±25	ns
	delay time difference between Y and colour-difference signals	Y delay; CTI and peaking off	70	100	130	ns
$t_{d(peak)(min)}$	minimum delay time for peaking		185	215	245	ns
G_Y	VBS signal gain measured on output pin 12 (composite signal, peak-to-peak value)	V_O/V_i ; f = 500 kHz; maximum delay	–2	–1	0	dB
I_{12}	output current (emitter-follower with constant current source)	source current	–1	–	–	mA
		sink current	0.4	–	–	mA
R_{12}	output resistance		–	–	160	Ω
f_{res}	frequency response for	maximum delay f = 0.5 to 3 MHz	–2	–1	0	dB
		f = 0.5 to 5 MHz	–4	–3	–1	dB
LIN	signal linearity for	$\alpha_{min}/\alpha_{max}$;				
	video contents of 315 mV (p-p)	$V_{VBS} = 450$ mV (p-p)	0.85	–	–	–
	video contents of 450 mV (p-p)	$V_{VBS} = 640$ mV (p-p)	0.60	–	–	–
Luminance peaking, selected via I²C-bus						
f_{peak}	peaking frequency	f_{C1} ; LCF-bit = 0	4.5	5	5.5	MHz
		f_{C2} ; LCF-bit = 1	2.3	2.6	2.9	MHz
V_{peak}	peaking amplitude for grade of peaking (f_C amplitude/0.5 MHz amplitude) selectable values		–	–3	–	dB
			–	0	–	dB
			–	+3	–	dB
			–	+6	–	dB
	limitation of peaking (positive amplitude of correction signal referenced to 315 mV)		–	20	–	%
$V_{n(rms)}$	noise voltage on pin 12 (RMS value)	without peaking; f = 0 to 5 MHz	–	–	1	mV
COR	coring of peaking (coring part referenced to 315 mV)	COR-bit = 1	–	20	–	%

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Colour-difference paths measured with transient times $t_r = t_f = 1 \mu s$; $t_{pH} \geq 1 \mu s$; $V_i = 1.33 V$ (p-p) on pins 3 and 7 and with burst key pulse $t_{BK} = 4 \mu s$						
$V_{i(CD)(p-p)}$	$\pm(R - Y)$ input signal (peak-to-peak value; pin 3)	75% colour bar	–	1.05	1.48	V
	$\pm(B - Y)$ input signal (peak-to-peak value; pin 7)	75% colour bar	–	1.33	1.88	V
	input transient sensitivity	$V_{3,7}/\delta t$	0.15	–	–	V/ μs
$V_{3,7}$	internal clamping voltage level		–	2.45	–	V
$I_{3,7}$	input current	outside clamping	–	–	± 1	μA
		during clamping	± 100	–	± 190	μA
$C_{3,7}$	input capacitance		–	6	12	pF
$V_{4,6}$	DC output voltage		–	2	–	V
$\Delta V_{4,6}$	output offset voltage	$R_S \leq 300 \Omega$; note 1	–	–	± 5	mV
		during and after storage time	–	–	± 18	mV
V_{spike}	spurious spike signals on pins 4 and 6	$R_S \leq 300 \Omega$; note 1	–	–	± 30	mV
$I_{4,6}$	output current (emitter-follower with constant current source)	source current	–1	–	–	mA
		sink current	0.4	–	–	mA
$R_{4,6}$	output resistance		–	–	100	Ω
G_v	signal gain in each path	V_o/V_i	–1	0	+1	dB
ΔG_v	gain difference $-(R - Y)/(B - Y)$		–	0	± 0.3	dB
LIN	signal linearity for nominal signal	$\alpha_{min}/\alpha_{max}$; $V_i = 1.33 V$ (p-p)	0.90	–	–	–
	+3 dB signal	$V_i = 1.88 V$ (p-p)	0.65	–	–	–
ΔV_o	signal reduction at higher frequency (output signal ratio V_i/V_o)	signal with $t_{pH} = 50 ns$; $t_r = t_f = 1 \mu s$	–1.5	–	–	dB
Sandcastle pulse, input voltage selectable via I²C-bus						
V_{17}	input voltage threshold for H and V sync	SC5-bit = 0 (+12 V)	1.1	1.5	1.9	V
	input voltage threshold for burst	SC5-bit = 0 (+12 V)	5.5	6.5	7.5	V
	input voltage threshold for H and V sync	SC5-bit = 1 (+5 V)	1.1	1.5	1.9	V
	input voltage threshold for burst	SC5-bit = 1 (+5 V)	3.0	3.5	4.0	V
R_{17}	input resistance	+12 V input level	30	40	50	k Ω
		+5 V input level	15	20	25	k Ω
C_{17}	input capacitance		–	4	8	pF
t_{BK}	burst key pulse width		3.0	4.0	4.6	μs
t_d	leading edge delay for clamping pulse	referenced to t_{BK}	–	1	–	μs
n_p	number of required burst key pulses vertical blanking interval	note 2	4	–	31	–

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I²C-bus control, SDA and SCL						
V _{IH}	HIGH level input voltage on pins 9 and 10		3	–	5	V
V _{IL}	LOW level input voltage		0	–	1.5	V
I _{9,10}	input current		–	–	±10	µA
V _{O(ACK)}	output voltage at acknowledge on pin 9	I _{O(ACK)} = 3 mA	–	–	0.4	V
I _{O(ACK)}	output current at acknowledge on pin 9	sink current	3	–	–	mA

Notes

1. Crosstalk on output, measured in the unused channel when the other channel is provided with a nominal input signal (CTI active).
2. A number of more than 31 burst key pulses repeats the counter cycle of delay time control.

I²C-BUS FORMAT

S ⁽¹⁾	SLAVE ADDRESS ⁽²⁾	ACK ⁽³⁾	SUBADDRESS ⁽⁴⁾	ACK ⁽³⁾	DATA ⁽⁵⁾	P ⁽⁶⁾
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Notes

1. S = START condition.
2. SLAVE ADDRESS = 1000 100X.
3. ACK = acknowledge, generated by the slave.
4. SUBADDRESS = subaddress byte, see Table 1.
5. DATA = data byte, see Table 1.
6. P = STOP condition.
7. X = read/write control bit.
X = 0, to write (the circuit is slave receiver only).

If more than 1 byte DATA is transmitted, then auto-increment of the subaddress is performed.

Table 1 I²C-bus transmission; see Table 2

FUNCTION	SUBADDRESS	DATA							
		D7	D6	D5	D4	D3	D2	D1	D0
Y delay/CTI/SC	00010000	0	SC5	CTI	DL4	DL3	DL2	DL1	DL0
Peaking and coring	00010001	COR	PEAK	LCF	0	0	0	PCON1	PCON0

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Table 2 Function of the bits

DATA	FUNCTION	LOGIC 1	LOGIC 0
DL0	set delay in luminance channel	45 ns	0 ns
DL1		90 ns	0 ns
DL2		180 ns	0 ns
DL3		180 ns	0 ns
DL4		450 ns	0 ns
CTI	set colour transient improvement	active	inactive
SC5	select sandcastle pulse voltage	+5 V	+12 V
LCF	set peaking frequency response	2.6 MHz	5.0 MHz
PEAK	set peaking delay	active	inactive
COR	set coring control	active	inactive
PCONx	set peaking amplification	see Table 3	

Table 3 Peaking amplification

PCON1	PCON0	GRADE OF PEAKING (dB)
0	0	−3
0	1	0
1	0	+3
1	1	+6

Remarks to the subaddress bytes

Subaddresses 00H to 0FH are reserved for colour decoders and RGB processors.

Subaddresses 10 and 11 only are acknowledged.

General call address is not acknowledged.

Power-on-reset: D7 to D1 bits of data bytes are set to logic 0, D0 bit is set to logic 1.

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INTERNAL CIRCUITRY

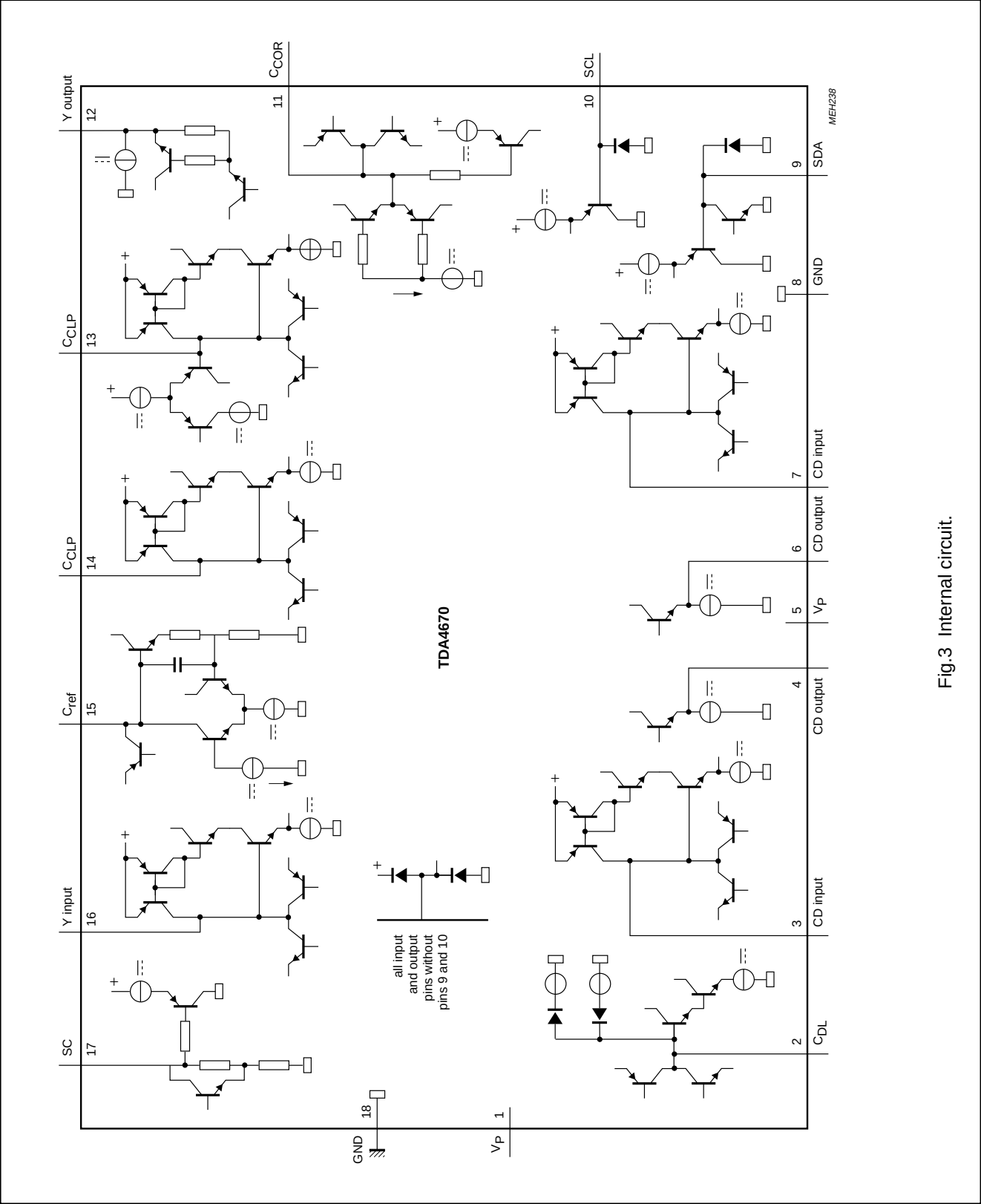


Fig.3 Internal circuit.

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TEST AND APPLICATION INFORMATION

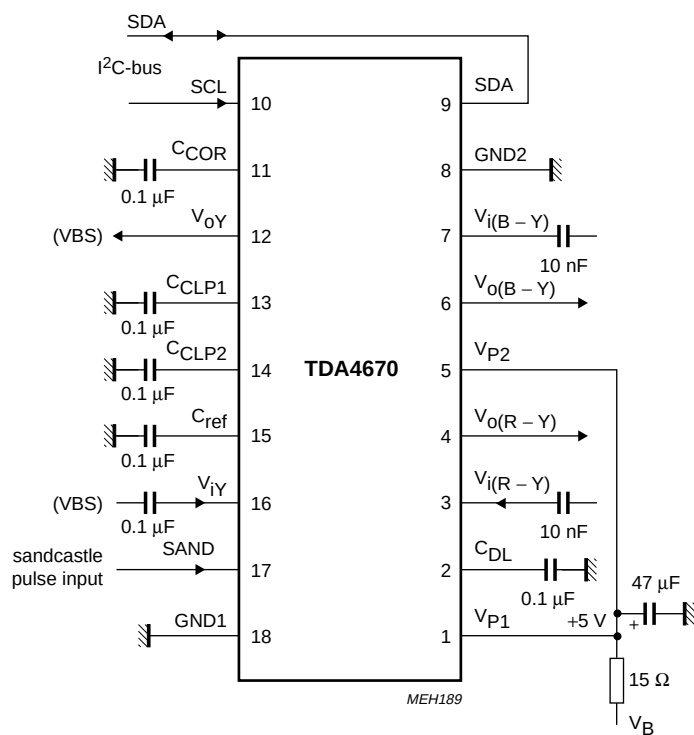


Fig.4 Test and application circuit.

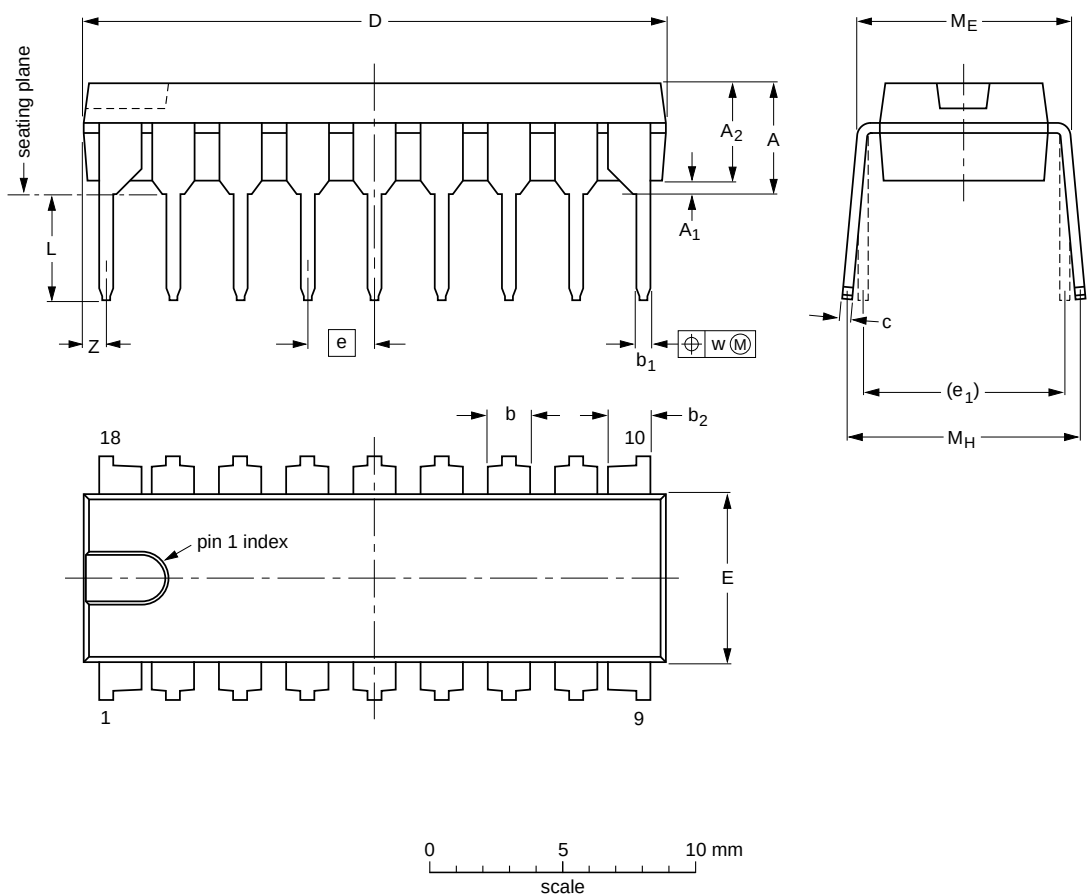
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PACKAGE OUTLINE

DIP18: plastic dual in-line package; 18 leads (300 mil)

SOT102-1

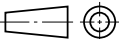


DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.7	0.51	3.7	1.40 1.14	0.53 0.38	1.40 1.14	0.32 0.23	21.8 21.4	6.48 6.20	2.54	7.62	3.9 3.4	8.25 7.80	9.5 8.3	0.254	0.85
inches	0.19	0.020	0.15	0.055 0.044	0.021 0.015	0.055 0.044	0.013 0.009	0.86 0.84	0.26 0.24	0.10	0.30	0.15 0.13	0.32 0.31	0.37 0.33	0.01	0.033

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT102-1						93-10-14 95-01-23

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SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "IC Package Databook" (order code 9398 652 90011).

Soldering by dipping or by wave

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact

with the joint for more than 5 seconds.

The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg\ max}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

Repairing soldered joints

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

PURCHASE OF PHILIPS I²C COMPONENTS



Purchase of Philips I²C components conveys a license under the Philips' I²C patent to use the components in the I²C system provided the system conforms to the I²C specification defined by Philips. This specification can be ordered using the code 9398 393 40011.

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NOTES

Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 34 Waterloo Road, NORTH RYDE, NSW 2113,
Tel. +61 2 9805 4455, Fax. +61 2 9805 4466

Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213,
Tel. +43 1 60 101, Fax. +43 1 60 101 1210

Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,
220050 MINSK, Tel. +375 172 200 733, Fax. +375 172 200 773

Belgium: see The Netherlands

Brazil: see South America

Bulgaria: Philips Bulgaria Ltd., Energoproject, 15th floor,
51 James Bourchier Blvd., 1407 SOFIA,
Tel. +359 2 689 211, Fax. +359 2 689 102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS,
Tel. +1 800 234 7381

China/Hong Kong: 501 Hong Kong Industrial Technology Centre,
72 Tat Chee Avenue, Kowloon Tong, HONG KONG,
Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America

Czech Republic: see Austria

Denmark: Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S,
Tel. +45 32 88 2636, Fax. +45 31 57 1949

Finland: Sinikalliontie 3, FIN-02630 ESPOO,
Tel. +358 9 615800, Fax. +358 9 61580/xxx

France: 4 Rue du Port-aux-Vins, BP317, 92156 SURESNES Cedex,
Tel. +33 1 40 99 6161, Fax. +33 1 40 99 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG,
Tel. +49 40 23 53 60, Fax. +49 40 23 536 300

Greece: No. 15, 25th March Street, GR 17778 TAVROS/ATHENS,
Tel. +30 1 4894 339/239, Fax. +30 1 4814 240

Hungary: see Austria

India: Philips INDIA Ltd, Shivsagar Estate, A Block, Dr. Annie Besant Rd.
Worli, MUMBAI 400 018, Tel. +91 22 4938 541, Fax. +91 22 4938 722

Indonesia: see Singapore

Ireland: Newstead, Clonskeagh, DUBLIN 14,
Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, TEL AVIV 61180,
Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Piazza IV Novembre 3,
20124 MILANO, Tel. +39 2 6752 2531, Fax. +39 2 6752 2557

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108,
Tel. +81 3 3740 5130, Fax. +81 3 3740 5077

Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,
Tel. +82 2 709 1412, Fax. +82 2 709 1415

Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,
Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,
Tel. +9-5 800 234 7381

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,
Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,
Tel. +64 9 849 4160, Fax. +64 9 849 7811

Norway: Box 1, Manglerud 0612, OSLO,
Tel. +47 22 74 8000, Fax. +47 22 74 8341

Philippines: Philips Semiconductors Philippines Inc.,
106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,
Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

Poland: Ul. Lukiska 10, PL 04-123 WARSZAWA,
Tel. +48 22 612 2831, Fax. +48 22 612 2327

Portugal: see Spain

Romania: see Italy

Russia: Philips Russia, Ul. Usatcheva 35A, 119048 MOSCOW,
Tel. +7 095 247 9145, Fax. +7 095 247 9144

Singapore: Lorong 1, Toa Payoh, SINGAPORE 1231,
Tel. +65 350 2538, Fax. +65 251 6500

Slovakia: see Austria

Slovenia: see Italy

South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,
2092 JOHANNESBURG, P.O. Box 7430 Johannesburg 2000,
Tel. +27 11 470 5911, Fax. +27 11 470 5494

South America: Rua do Rocio 220, 5th floor, Suite 51,
04552-903 São Paulo, SÃO PAULO - SP, Brazil,
Tel. +55 11 821 2333, Fax. +55 11 829 1849

Spain: Balmes 22, 08007 BARCELONA,
Tel. +34 3 301 6312, Fax. +34 3 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM,
Tel. +46 8 632 2000, Fax. +46 8 632 2745

Switzerland: Allmendstrasse 140, CH-8027 ZÜRICH,
Tel. +41 1 488 2686, Fax. +41 1 481 7730

Taiwan: PHILIPS TAIWAN Ltd., 23-30F, 66,
Chung Hsiao West Road, Sec. 1, P.O. Box 22978,
TAIPEI 100, Tel. +886 2 382 4443, Fax. +886 2 382 4444

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd.,
209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260,
Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL,
Tel. +90 212 279 2770, Fax. +90 212 282 6707

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes,
MIDDLESEX UB3 5BX, Tel. +44 181 730 5000, Fax. +44 181 754 8421

United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,
Tel. +1 800 234 7381

Uruguay: see South America

Vietnam: see Singapore

Yugoslavia: PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,
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Building BE-p, P.O. Box 218, 5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

Internet: <http://www.semiconductors.philips.com>

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